

<b>INFORMATION DISCLOSURE CITATION</b> <i>(Use several sheets if necessary)</i>	Atty. Docket No. <u>35.C5745 CIP/CII/DII</u>	Application No. <u>08/479,000</u>
	Applicant <u>SEISHIRO YOSHIOKA ET AL.</u>	
	Filing Date <u>June 7, 1995</u>	Group/ <u>2211</u>

## **U.S. PATENT DOCUMENTS**

*Examiner Initial	Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate
<i>JPK</i>	4 0 9 3 5 6 2	6/6/78	Kishimoto	252	511	
<i>JPK</i>	4 3 2 5 0 8 4	4/13/82	Van Gorkom et al.	313	346	
<i>JPK</i>	3 2 7 8 7 8 9	10/11/66	Shroff	313	346	
<i>JPK</i>	3 7 3 5 1 8 6	5/23/73	Klopfer et al.	313	346	

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## FOREIGN PATENT DOCUMENTS

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SEARCHED PATENT DOCUMENTS									
SEARCHED	SEARCHED	SEARCHED	SEARCHED	SEARCHED	SEARCHED	SEARCHED	SEARCHED	SEARCHED	TRANSLATION
									Yes No
	UK	2 0 6 0 9 9 1	5/17/81	United Kingdom					X
	SU	8 5 5 7 8 2	8/15/81	Soviet Union					Abstract Only
	DE	2 4 1 3 9 4 2	2/15/79	Germany					U.S. 3,998,678
	DE	1 8 0 0 9 5 2	7/22/71	Germany					Abstract Only
	DE	2 5 4 2 3 4 9	7/10/76	Germany					Abstract Only
	DE	2 0 1 2 1 0 1	3/6/78	Germany					U.S. 3,678,325
	DE	1 7 6 4 9 9 4	1/13/72	Germany					Abstract Only
	EP	0 0 7 3 0 3 1	3/2/83	Europe					Abstract Only
	GB	1 2 6 7 0 2 9	3/5/72	Great Britain					X
	GB	1 3 3 5 9 7 9	10/3/73	Great Britain					X
	JP	56-1 8 3 3 6	2/21/81	Japan (ABSTRACT ONLY)					Abstract Only
	JP	56-7 1 2 3 9	6/13/81	Japan (ABSTRACT ONLY)					Abstract Only

**OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Page, Etc.)**

- M. Hartwell et al., "Strong Electron Emission From patterned Tin-indium Oxide Thin Films" Cambridge MA, pp. 519-521, IEEE TRANSL. GD Conf., 1975
- M. Elinson et al., "The Emission of Hot Electrons And The Field Emissions Of Electrons From Tin Oxide", Radio Engineering and Electron Physics, JULY 1965, pp. 1291-1296

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**EXAMINER**

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## U.S. PATENT DOCUMENTS

*Examiner Initial	Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate
JKR	3 6 6 3 8 5 7	5/16/72	A.M. Soellner et al.	313	339	

## FOREIGN PATENT DOCUMENTS

JKR	Document Number	Date	Country	Translation		Yes	No
				Class	Subclass		
JKR	44 - 2 6 1 2 5	1/4/69	Japan				
JKR	46 - 2 0 9 4 9	6/12/71	Japan				
JKR	44 - 2 7 8 5 2	11/18/44	Japan				
JKR	46 - 3 8 0 6 0	11/9/71	Japan				
JKR	45 - 3 1 6 1 5	10/13/70	Japan				
JKR	44 - 2 7 8 5 3	11/18/69	Japan				
JKR	44 - 2 8 0 0 9	11/19/69	Japan				
JKR	46 - 2 4 4 5 6	7/14/71	Japan				
JKR	44 - 3 2 2 4 7	12/23/69	Japan				
JKR	46 - 2 0 9 4 3	6/12/71	Japan				
JKR	46 - 2 0 9 4 4	6/12/71	Japan				
JKR	54 - 1 1 4 7	1/20/79	Japan				

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## OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Page, Etc.)

EXAMINER	DATE CONSIDERED
JKR	5/16/96

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F511/A502809

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